# AC6376F Datasheet

# Zhuhai Jieli Technology Co.,LTD

Version: 1.0

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## **AC6376F Features**

#### **CPU**

- 32-bit DSP supports hardware Float Point Unit(FPU)
- Up to 160MHz programmable processor
- 64Vectored interrupts
- 4 Levels interrupt priority

#### **Bluetooth**

- Compliant with BluetoothV5.1+BR+EDR+BLE specification
- Meet class1 class2 and class3 transmitting power requirement
- Support GFSK and π/4 DQPSK all packet types
- Provides maximum+8dbm transmitting power
- receiver with -94dBm sensitivity
- Fast AGC for enhanced dynamic range
- Supports
  A2DP\AVCTP\AVDTP\AVRCP\HFP\SPP\
  SMP\ATT\GAP&GATT\RFCCOMM\SDP\
  L2CAP profile

#### **Peripherals**

- One full speed USB 2.0 OTG controller
- Six multi-function 32-bit timers, support capture and PWM mode
- Three full-duplex basic UART, support DMA

#### mode

- One hardware IIC interface supports host and device mode
- Two Built-in low power Cap Sense Keys
- Built-in Cap Sense Key controller
- 10-bit ADC for analog sampling
- External wake up/interrupt on all GPIOs

#### **PMU**

- Low voltage LDO and DC-DC for internal digital and analog circuit supply
- 2uA current consumption in the soft-off mode
- Built-in LDO and DC-DC for the core, I/O,
  Bluetooth and flash
- **VBAT** is 2.0V to 4.5V
- VDDIO is 2.0V to 3.4V

#### **Packages**

**QFN32(4mm\*4mm)** 

#### **Temperature**

- Operating temperature: -40°Cto+85°C
- Storage temperature: -65°C to +150°C

#### **Applications**

Bluetooth IOT

## 1, Pin Definition

## 1.1 Pin Assignment

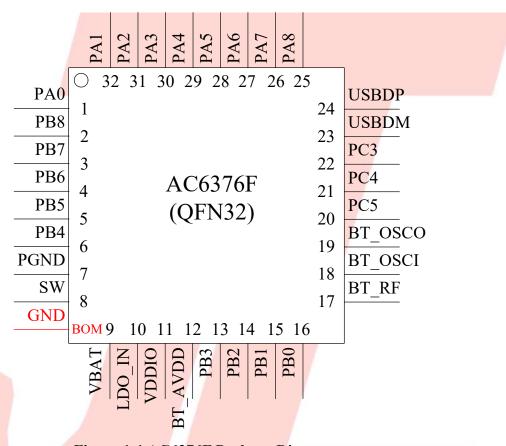


Figure 1-1 AC6376F Package Diagram

## 1.2 Pin Description

**Table 1-1 AC6376F Pin Description** 

PIN	Name	I/O	Drive	Function	Other Function
NO.		Type	(mA)		
1	DA O	I/O	0	GPIO	
1	PA0	I/O	8	(High Voltage Input)	
2	PB8	I/O	8/24	GPIO	UART0RXB: Uart0 Data Input(B);
		1/0	0/21	Grio	CAP4: Timer4 Capture;
					UART0TXB: Uart0 Data Output(B);
3	PB7	I/O	8/24	GPIO	SPIIDOA: SPII Data Out(A);
				1 1	Q-decoder1;
					UART1RXA: Uart1 Data Input(A);
			/	7 /	SPI1CLKA: SPI1 Clk(A);
4	PB6	I/O	8/24	GPIO	PWM2: Timer2 PWM Output;
			6/24		ADC9: ADC Input Channel 9;
			/		Touch7: Touch Input Channel 7;
				7	Q-decoder0;
			1		SPI1DIA: SPI1 Data Input(A);
5	PB5	I/O	8/24	GPIO	ADC8: ADC Input Channel 8;
6					UART1TXA: Uart1 Data Output(A);
6	PB4	I/O	8/24	GPIO	ADC12: ADC Input Channel 12;
O	rb4	1/0	0/24	GPIO	TMR2: Timer2 Clock Input;
7	PGND	P	/	7 1	DCDC Ground
8	SW	P	/	DCDC output	DCDC switch output, connected to inductor
9	VBAT	P	1	A	connect to battery
				/	Charge Power Input;
					UART0TXC: Uart0 Data Output(C);
10	LDO_IN	P	/		UART0RXC: Uart0 Data Input(C);
					PWM3: Timer3 PWM Output;
					CAP1: Timer1 Capture;
11	VDDIO	P	/		IO Power 3.3v
12	BT_AVDD	P	/		BT Power
13	PB3	I/O	8/24	GPIO	
					SPI2DOC: SPI2 Data Out(C);
					ADC7: ADC Input Channel 7;
14	PB2	I/O	8/24	GPIO	UART2RXC: Uart2 Data Input(C);
					CAP5: Timer5 Capture;
					LP_TH1: Low Power Touch Channel 1;

				I		
					Long Press Reset;	
15	PB1	I/O	8/24	GPIO	UART2TXC: Uart2 Data Output(C);	
				(pull up)	ADC6: ADC Input Channel 6;	
					LP_TH0: Low Power Touch Channel 0;	
16	PB0	I/O	8	GPIO (High Voltage Input)	SPI2DIC: SPI2 Data Input(C);	
17	BT_RF	/	/		BT Antenna	
18	BT_OSCI	I	/		BTOSC In	
19	BT_OSCO	О	/		BTOSC Out	
					UART2RXD: Uart2 Data Input(D);	
20	DC5	1/0	0/24	CDIO	SPI1DOB: SPI1 Data Out(B);	
20	PC5	I/O	8/24	GPIO	IIC_SDA_B: IIC SDA(B);	
					ADC5: ADC Input Channel 5;	
					UART2TXD: Uart2 Data Output(D);	
					SPI1CLKB: SPI1 Clk(B);	
21	PC4	I/O	8/24	GPIO	IIC_SCL_B: IIC SCL(B);	
					ADC4: ADC Input Channel 4;	
					PWM4: Timer4 PWM Output;	
22	PC3	I/O	8/24	GPIO	UART0RXD: Uart0 Data Input(D);	
					UART1RXD: Uart1 Data Input(D);	
22	Habby	1/0	/,	USB Negative Data	SPI2DOB: SPI2 Data Out(B);	
23	USBDM	I/O	4	(pull down)	IIC_SDA_A: IIC SDA(A);	
					ADC11: ADC Input Channel 11;	
1				7./	UART1TXD: Uart1 Data Output(D);	
0.4	HGDDD	1/0	4	USB Positive Data	SPI2CLKB: SPI2 Clk(B);	
24	USBDP	I/O	4	(pull down)	IIC_SCL_A: IIC SCL(A);	
				7.	ADC10: ADC Input Channel 10;	
				/ /	ADC3: ADC Input Channel 3;	
25	PA8	I/O	8/24	GPIO	UART2RXB: Uart2 Data Input(B);	
1/2					Touch5: Touch Input Channel 5;	
26	DA7	1/0	0/24	CDIO	UART2TXB: Uart2 Data Output(B);	
26	PA7	I/O	8/24	GPIO	Touch4: Touch Input Channel 4;	
	1)				SPI2DOA: SPI2 Data Out(A);	
					IIC_SDA_D: IIC SDA(D);	
27	DA6	I/O	8/24	GPIO	ADC2: ADC Input Channel 2;	
21	PA6	1/0	0/24	Grio	UART0RXA: Uart0 Data Input(A);	
					CAP0: Timer0 Capture;	
					Touch3: Touch Input Channel 3;	

28	PA5	I/O	8/24	GPIO	SPI2CLKA: SPI2 Clk(A); IIC_SCL_D: IIC SCL(D); ADC1: ADC Input Channel 1; UART0TXA: Uart0 Data Output(A); PWM5: Timer5 PWM Output; Touch2: Touch Input Channel 2;
29	PA4	I/O	8/24	GPIO	SPI2DIA: SPI2 Data Input(A); UART2RXA: Uart2 Data Input(A); CAP2: Timer2 Capture; OSC32KI: 32KHz OSC In; Touch1: Touch Input Channel 1;
30	PA3	I/O	8/24	GPIO	UART2TXA: Uart2 Data Output(A); ADC0: ADC Input Channel 0; PWM1: Timer1 PWM Output;; OSC32KO: 32KHz OSC Out; Touch0: Touch Input Channel 0;
31	PA2	I/O	8/24	GPIO	SPI1CLKC: SPI1 Clk(C); UART1RXC: Uart1 Data Input(C); CAP3: Timer3 Capture;
32	PA1	I/O	8/24	GPIO	SPI1DIC: SPI1 Data Input(C); UART1TXC: Uart1 Data Output(C); PWM0: Timer0 PWM Output;
	Substrate	Р	/	GND	-

## 2. Electrical Characteristics

## 2.1 Absolute Maximum Ratings

Table 2-1

Symbol	Parameter	Min	Max	Unit
Tamb	Ambient Temperature	-40	+85	°C
Tstg	Storage temperature	-65	+150	°C
VBAT	Supply Voltage	-0.3	5	V
LDO_IN	Charger Voltage	-0.3	6	V
V <sub>3.3IO</sub>	3.3V IO Input Voltage	-0.3	3.6	V

Note: The chip can be damaged by any stress in excess of the absolute maximum ratings listed below

## 2.2 Recommended Operating Conditions

Table 2-2

Symbol	Parameter	Min	Тур	Max	Unit	Test Conditions	
VBAT	Voltage Input	2.0	3.7	4.5	V		
LDO_IN	Charger Voltage	4.5	5.0	5.5	V		
V <sub>3.3</sub>	Voltage output	2.0	3.0	3.4	V	VBAT = 4.2V, 100mA loading	
V <sub>BT_AVDD</sub>	Voltage output	1.2	1.25	1.35	V	VBAT=4.2V, 100mA loading	
I <sub>L3.3</sub>	Loading current	_	_//	150	mA	VBAT = 4.2V	

## 2.3 Battery Charge

**Table 2-3** 

Symbol	Parameter	Min	Тур	Max	Unit	Test Conditions
LDO_IN	Charge Input Voltage	4.5	5	5.5	V	-
$ m V_{Charge}$	Charge Voltage	4.15	4.2	4.25	V	-
$ m I_{Charge}$	Charge Current	20		200	mA	Charge current at fast charge mode
$I_{Trikl}$	Trickle Charge Current	20	45	70	mA	$V_{\mathrm{BAT}}\!\!<\!\!V_{\mathrm{Trikl}}$

## 2.4 IO Input/Output Electrical Logical Characteristics

Table 2-4

IO input characteristics								
Symbol	Parameter	Min	Тур	Max	Unit	Test Conditions		
$V_{\rm IL}$	Low-Level Input Voltage	-0.3	-	0.3* VDDIO	V	VDDIO = 3.3V		
$ m V_{IH}$	High-Level Input Voltage	0.7* VDDIO	-	VDDIO+0.3	V	VDDIO = 3.3V		
IO output o	characteristi <mark>cs</mark>							
$V_{OL}$	Low-Level Output Voltage	-	_	0.33	V	VDDIO = 3.3V		
V <sub>OH</sub>	High-Level Output Voltage	2.7	-	-	V	VDDIO = 3.3V		

## 2.5 Internal Resistor Characteristics

Table 2-5

	Port	General Output	High Drive	Internal Pull-Up Resistor	Internal Pull-Down Resistor	Comment
	PA1~PA8, PB1~PB8, PC3~PC5,	8mA	24mA	10K	10K	1、PB1 default pull up
1	PA0,PB0	8mA	8mA	10K	10K	2、USBDM & USBDP default pull down 3、internal pull-up/pull-down
	USBDP	4mA	_	1.5K	15K	resistance   accuracy ±20%
	USBDM	4mA	_	180K	15K	

## 2.6 BT Characteristics

#### 2.6.1 Transmitter

Basic Data Rate

**Table 2-6** 

Paramete	Min	Тур	Max	Unit	Test Conditions	
RF Transmit P	ower		6	8	dBm	
RF Power Contro	l Range		20		dB	25℃,
20dB Bandwidth			950		KHz	Power Supply
	+2MHz		-40		dBm	
Adjacent Channel	-2MHz		-38		dBm	VBAT=5V
Transmit Power	+3MHz		-44		dBm	2441MHz
	-3MHz		-35		dBm	

#### **Enhanced Data Rate**

**Table 2-7** 

Paramete	Min	Тур	Max	Unit	Test Conditions	
Relative Po	Relative Power				dB	
π/4 DQPSK	DEVM RMS		6		%	
	DEVM 99%		10		%	25℃,
Modulation Accuracy	Modulation Accuracy DEVM Peak		15		%	Power Supply
	+2MHz		-40		dBm	VBAT=5V
Adjacent Channel	-2MHz		-38		dBm	2441MHz
Transmit Power	+3MHz		-44		dBm	
	-3MHz		-35		dBm	

#### 2.6.2 Receiver

#### **Basic Data Rate**

Table 2-8

Paramete	Min	Тур	Max	Unit	<b>Test Conditions</b>	
Sensitivit		-94		dBm		
Co-channel Interferer	nce Rejection		-13		dB	
	+1MHz		+5		dB	25℃,
	-1MHz		+2		dB	Power Supply
Adjacent Channel	+2MHz		+37		dB	VBAT=5V
Interference Rejection	-2MHz		+36		dB	2441MHz
	+3MHz		+40		dB	
	-3MHz	7/	+35		dB	

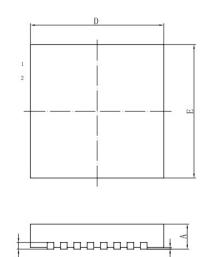
### **Enhanced Data Rate**

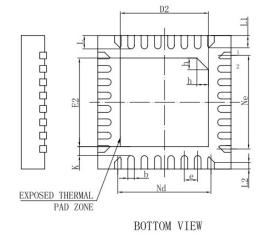
Table 2-9

Parameter		Min	Тур	Max	Unit	Test Conditions
Sensitivit	Sensitivity				dBm	
Co-channel Interferen	nce Rejection		-13		dB	
4/1/2	+1MHz		+5		dB	25℃,
	-1MHz		+2		dB	Power Supply
Adjacent Channel	+2MHz		+37		dB	VBAT=5V
Interference Rejection	-2MHz		+36		dB	2441MHz
	+3MHz		+40		dB	
	-3MHz		+35		dB	

# 3. Package Information

## 3.1 QFN32(4mm\*4mm)





SYMBOL	MILLIMETER		
SIMBOL	MIN	NOM	MAX
A	0.70	0.75	0.80
Al	0	0.02	0.05
b	0.15	0.20	0. 25
c	0.18	0.20	0.25
D	3.90	4.00	4.10
D2	2.60	2.65	2.70
e	0. 40BSC		
Nd	2. 80BSC		
E	3. 90	4.00	4. 10
E2	2.60	2.65	2.70
Ne	2. 80BSC		
K	0. 20	150	-
L	0.35	0.40	0.45
L1	0.30	0.35	0.40
L2	0.15	0.20	0. 25
h	0.30	0.35	0.40
/F载体尺寸 (161)	112*112		

Figure 3-1 AC6376F Package

## 4. Revision History

Date	Revision	Description		
2020.11.04	V1.0	Initial Release		

